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Dual JK Flip-Flop (with Separate Clear and Clock)

## RENESAS

ADE-205-363 (Z) 1st. Edition Sep. 2000

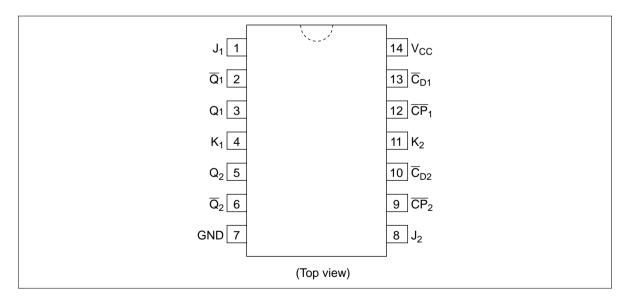
#### Description

The HD74AC107/HD74ACT107 dual JK master/slave flip-flops have a separate clock for each flip-flop. Inputs to the master section are controlled by the clock pulse. The clock pulse also regulates the state of the coupling transistors which connect the master and slave sections. The sequence of operation is as follows: 1) isolate slave from master; 2) enter information from J and K inputs to master; 3) disable J and K inputs; 4) transfer information from master to slave.

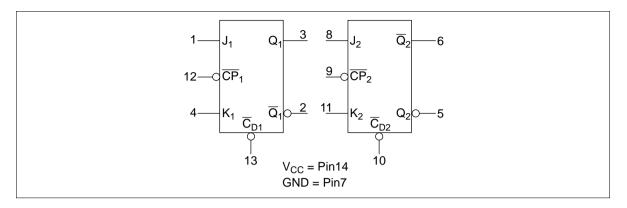
#### Features

- Outputs Source/Sink 24 mA
- HD74ACT107 has TTL-Compatible Inputs

### **Pin Arrangement**



## Logic Symbol



#### **Pin Names**

<b>J</b> <sub>1</sub> , <b>J</b> <sub>2</sub> , <b>K</b> <sub>1</sub> , <b>K</b> <sub>2</sub>	Data Inputs
$\overline{CP}_1, \overline{CP}_2$	Clock Pulse Inputs (Active Falling Edge)
$\overline{C}_{D1}, \overline{C}_{D2}$	Direct Clear Inputs (Active Low)
$\mathbf{Q}_1, \mathbf{Q}_2, \overline{\mathbf{Q}}_1, \overline{\mathbf{Q}}_2$	Outputs

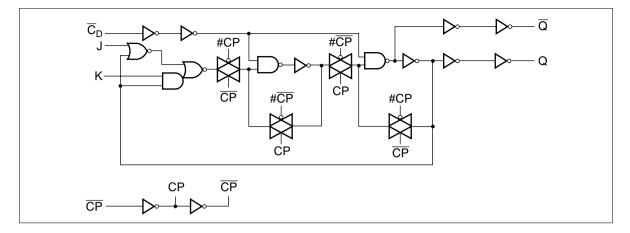
#### **Truth Table**

Inpu	uts			Outputs
@ t	ı			@ t <sub>n+1</sub>
J			К	Q
L			L	Qn
L			Н	L
Н			L	Н
Н			Н	Qn
Н	:	High Voltage Level Low Voltage Level		
L	:	Low Voltage Level		

 $t_n$  : Bit time before clock pulse.

 $t_{n+1}$  : Bit time after clock pulse.

### Logic Diagram



### DC Characteristics (unless otherwise specified)

Item	Symbol	Max	Unit	Condition
Maximum quiescent supply current	I <sub>cc</sub>	40	μΑ	$V_{IN} = V_{CC}$ or ground, $V_{CC} = 5.5 V$ , Ta = Worst case
Maximum quiescent supply current	I <sub>cc</sub>	4.0	μΑ	$V_{IN} = V_{CC}$ or ground, $V_{CC} = 5.5$ V, Ta = 25°C
Maximum additional I <sub>cc</sub> /input (HD74ACT107)	I <sub>CCT</sub>	1.5	mA	$V_{IN} = V_{CC} - 2.1 \text{ V}, V_{CC} = 5.5 \text{ V}$ Ta = Worst case



## AC Characteristics: HD74AC107

			Ta = +25°C C∟= 50 pF				Ta = −40°C to +85°C C <sub>∟</sub> = 50 pF		
Item	Symbol	V <sub>cc</sub> (V)* <sup>1</sup>	Min	Тур	Max	Min	Max	Unit	
Maximum clock	$f_{max}$	3.3	125		_	100	—	MHz	
frequency		5.0	150		—	125	—		
Propagation delay	t <sub>PLH</sub>	3.3	1.0	9.5	13.0	1.0	14.0	ns	
$\overline{C}_{P}$ to Q or $\overline{Q}$		5.0	1.0	7.5	10.0	1.0	11.0		
Propagation delay	t <sub>PHL</sub>	3.3	1.0	10.0	13.5	1.0	14.5	ns	
$\overline{C}_{P}$ to Q or $\overline{Q}$		5.0	1.0	8.0	10.5	1.0	11.5	_	
Propagation delay	t <sub>PLH</sub>	3.3	1.0	9.5	13.0	1.0	14.0	ns	
$\overline{C}_{D}$ to $\overline{Q}$		5.0	1.0	7.5	10.0	1.0	11.0	_	
Propagation delay	t <sub>PHL</sub>	3.3	1.0	9.5	13.0	1.0	14.0	ns	
$\overline{C}_{D}$ to $\overline{Q}$		5.0	1.0	7.5	10.0	1.0	11.0	_	

Note: 1. Voltage Range 3.3 is 3.3 V  $\pm$  0.3 V Voltage Range 5.0 is 5.0 V  $\pm$  0.5 V

#### **Operating Requirements: HD74AC107**

			Ta = +25°C C <sub>∟</sub> = 50 pF		Ta = −40°C to +85°C C <sub>L</sub> = 50 pF	
Item	Symbol	V <sub>cc</sub> (V)* <sup>1</sup>	Тур	Guaranteed Minimum		Unit
Setup time	t <sub>su</sub>	3.3	3.0	5.5	6.0	ns
J or k to $\overline{C}_{P}$		5.0	2.0	4.0	4.5	_
Hold time	t <sub>h</sub>	3.3	-1.5	0.0	0.0	_
$\overline{C}_{P}$ to J or k		5.0	-0.5	0.0	0.0	_
Pulse width	t <sub>w</sub>	3.3	2.0	5.5	7.0	_
$\overline{C}_{P}$ or $\overline{C}_{D}$		5.0	2.0	4.5	5.0	_
Recovery time	t <sub>rec</sub>	3.3	1.5	3.0	3.0	_
$\overline{C}_{D}$ to $\overline{C}_{P}$		5.0	1.0	3.0	3.0	_

Note: 1. Voltage Range 3.3 is 3.3 V  $\pm$  0.3 V Voltage Range 5.0 is 5.0 V  $\pm$  0.5 V

## AC Characteristics: HD74ACT107

			Ta = +25°C C <sub>∟</sub> = 50 pF			Ta = –4 C <sub>∟</sub> = 50		
Item	Symbol	V <sub>cc</sub> (V)* <sup>1</sup>	Min	Тур	Max	Min	Max	Unit
Maximum clock frequency	$f_{max}$	5.0	100	_	_	80	—	MHz
Propagation delay $\overline{C}_{P}$ to Q or $\overline{Q}$	t <sub>PLH</sub>	5.0	1.0	9.5	12.5	1.0	13.5	ns
Propagation delay $\overline{C}_{P}$ to Q or $\overline{Q}$	t <sub>PHL</sub>	5.0	1.0	10.5	13.0	1.0	14.0	
$\frac{\text{Propagation delay}}{\overline{C}_{D} \text{ to } \overline{Q}}$	t <sub>PLH</sub>	5.0	1.0	8.5	11.0	1.0	12.0	
$\frac{Propagation}{\overline{C}_{D}} \text{ to } Q$	t <sub>PHL</sub>	5.0	1.0	8.5	11.0	1.0	12.0	

Note: 1. Voltage Range 5.0 is 5.0 V  $\pm$  0.5 V

#### **Operating Requirements: HD74ACT107**

			Ta = +25°C C <sub>∟</sub> = 50 pF		Ta = −40°C to +85°C C <sub>L</sub> = 50 pF	
Item	Symbol	V <sub>cc</sub> (V)* <sup>1</sup>	Тур	Guaranteed	Minimum	Unit
Setup time J or k to $\overline{C}_{P}$	t <sub>su</sub>	5.0	2.5	7.0	8.0	ns
Hold time $\overline{C}_{P}$ to J or k	t <sub>h</sub>	5.0	0.0	1.5	1.5	_
Pulse width $\overline{C}_{P}$ or $\overline{C}_{D}$	t <sub>w</sub>	5.0	4.5	7.0	8.0	_
Recovery time $\overline{C}_{D}$ to $\overline{C}_{P}$	t <sub>rec</sub>	5.0	_	3.0	3.0	_

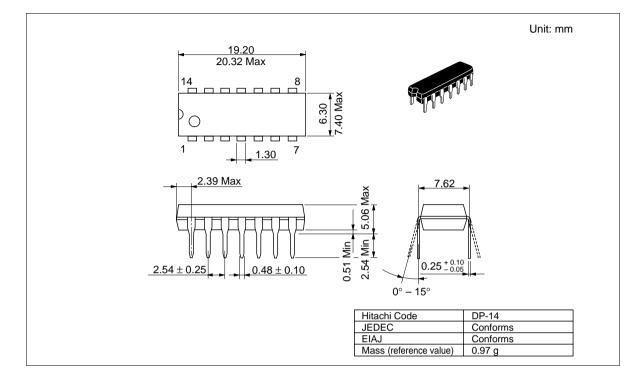
Note: 1. Voltage Range 5.0 is  $5.0 \text{ V} \pm 0.5 \text{ V}$ 

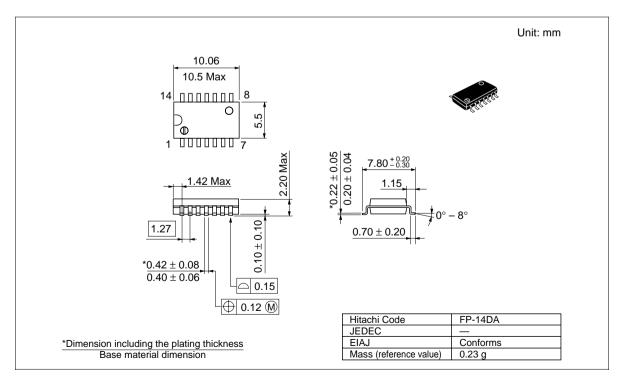
#### Capacitance

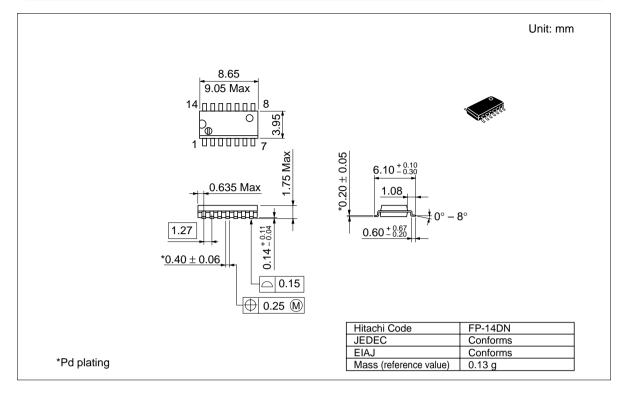
Item	Symbol	Тур	Unit	Condition
Input capacitance	CIN	4.5	pF	$V_{cc} = 5.5 V$
Power dissipation capacitance	C <sub>PD</sub>	35.0	pF	$V_{cc} = 5.0 V$



#### **Package Dimensions**







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